



YEA SHIN TECHNOLOGY CO., LTD

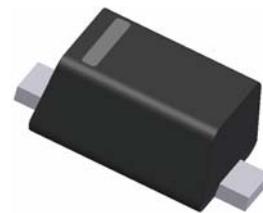
RB751S-40

**200mW SOD-523 SURFACE MOUNT
Very Small Outline Flat Lead Plastic Package
Schottky Barrier Diode**

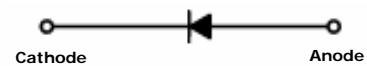
Absolute Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
P_D	Power Dissipation	200	mW
T_{STG}	Storage Temperature Range	-55 to +125	°C
T_J	Operating Junction Temperature	+125	°C
V_{RM}	Peak Reverse Voltage	40	V
V_R	Reverse Voltage	30	V
I_F	Forward Current	30	mA
I_{FPM}	Non-Repetitive Peak Forward Current	500	mA

These ratings are limiting values above which the serviceability of the diode may be impaired.



SOD-523 Flat Lead



ELECTRICAL SYMBOL

Specification Features:

- Low Forward Voltage Drop
- Flat Lead SOD-523 Small Outline Plastic Package
- Extremely Small SOD-523 Package
- Surface Device Type Mounting
- RoHS Compliant
- Matte Tin(Sn) Lead Finish
- Band Indicates Cathode

DEVICE MARKING CODES:

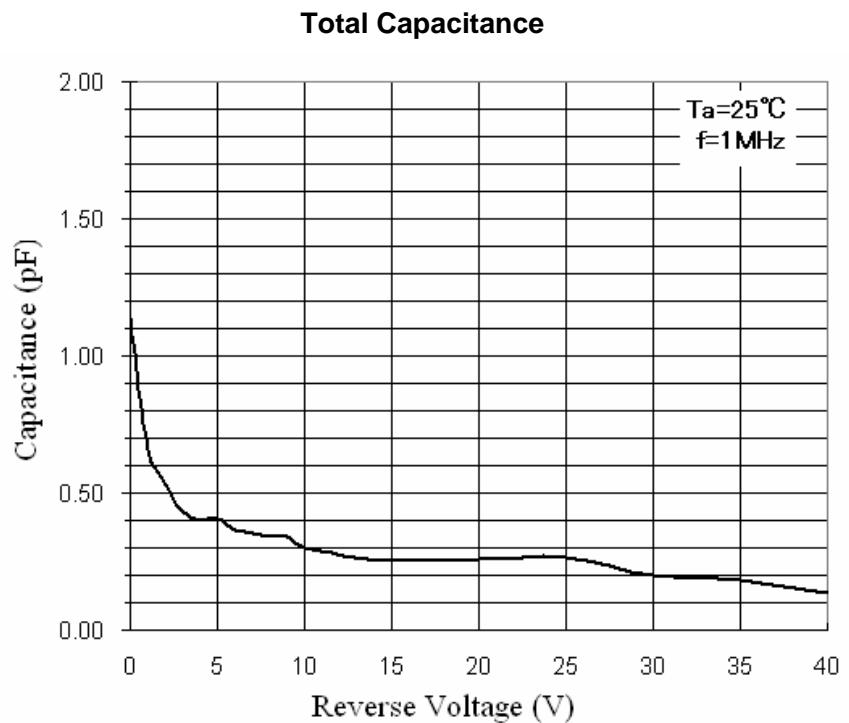
Device Type	Device Marking
RB751S-40	4B

Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

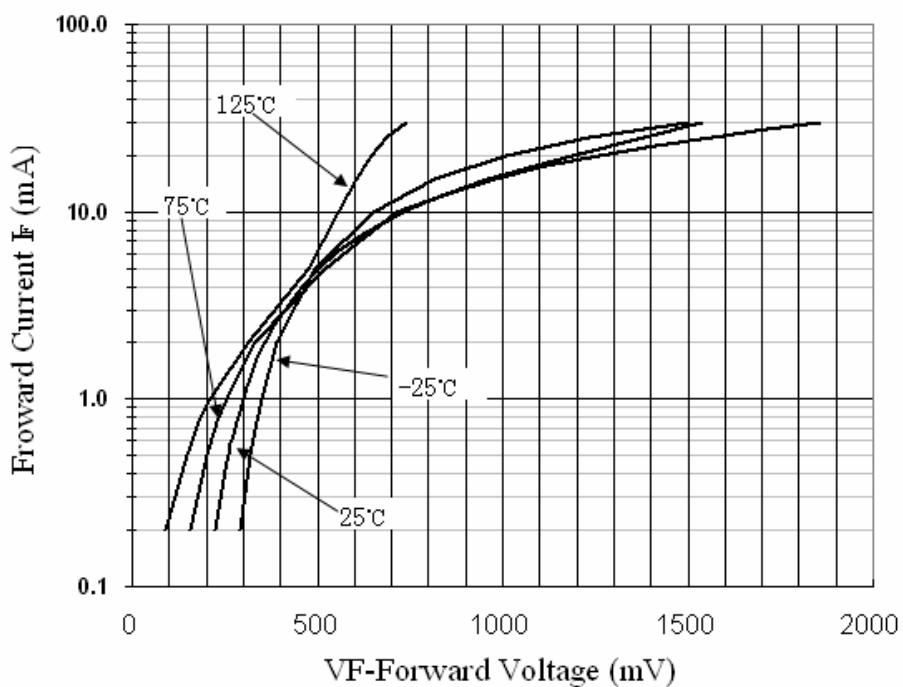
Symbol	Parameter	Test Condition	Limits		Unit
			Min	Max	
B_V	Breakdown Voltage	$I_R=10\mu\text{A}$	30		Volts
I_R	Reverse Leakage Current	$V_R=30\text{V}$		0.5	μA
V_F	Forward Voltage	$I_F=1\text{mA}$		0.37	Volts

DEVICE CHARACTERISTICS

RB751S-40



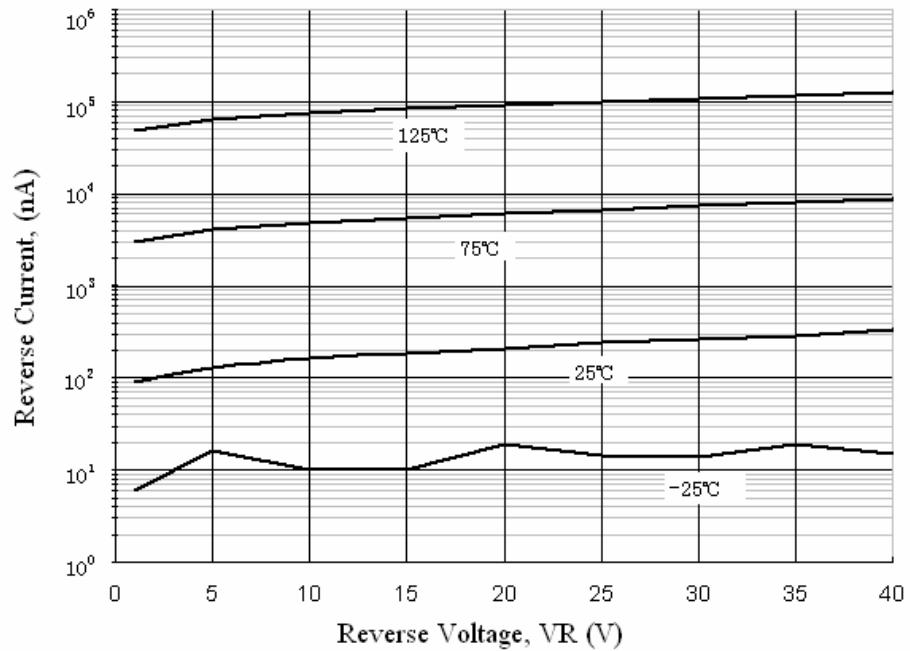
Forward Voltage vs Ambient Temperature



PACKAGE OUTLINE & DIMENSIONS

RB751S-40

Reverse Current vs Reverse Voltage



Flat Lead SOD-523 Package Outline

